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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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LOW NOISE AMPLIFIER MODULE. 29 - 36 GHz



v05.0711

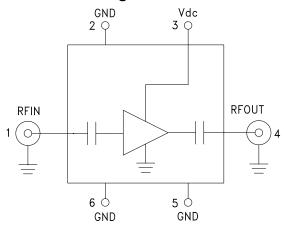


Typical Applications

The HMC-C027 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

Noise Figure: 2.9 dB

Gain: 20 dB OIP3: 22 dBm

P1dB Output Power: +11 dBm 50 Ohm Matched Input/Output Hermetically Sealed Module

Field Replaceable 2.92 mm Connectors -55 °C to +85 °C Operating Temperature

General Description

The HMC-C027 is a GaAs MMIC pHEMT Low Noise Amplifier in a miniature, hermetic module which operates between 29 and 36 GHz. This high dynamic range amplifier module provides 20 dB of gain, 2.9 dB noise figure and up to +22 dBm of output IP3 from a single +3V supply. The wideband amplifier I/Os are internally matched to 50 Ohms and DC blocked for robust performance. The module features positive gain slope, and consistent noise figure and output power performance across its operating band.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdc = +3V

| Parameter | Min. | Тур. | Max. | Units |
|--|------|---------|------|--------|
| Frequency Range | | 29 - 36 | | GHz |
| Gain | 17 | 20 | | dB |
| Gain Variation Over Temperature | | 0.03 | 0.05 | dB/ °C |
| Noise Figure | | 2.9 | 3.5 | dB |
| Input Return Loss | | 14 | | dB |
| Output Return Loss | | 8 | | dB |
| Output Power for 1 dB Compression (P1dB) | 8 | 11 | | dBm |
| Saturated Output Power (Psat) | | 13 | | dBm |
| Output Third Order Intercept (IP3) | | 22 | | dBm |
| Supply Current | | 80 | | mA |

HMC-C027* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS 🖳

View a parametric search of comparable parts.

DOCUMENTATION

Application Notes

 AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers

Data Sheet

· HMC-C027 Data Sheet

TOOLS AND SIMULATIONS \Box

• HMC-C027 S-Parameter

DESIGN RESOURCES

- HMC-C027 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC-C027 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK 🖳

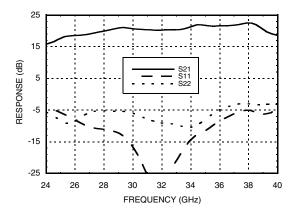
Submit feedback for this data sheet.



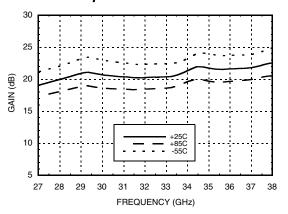


LOW NOISE AMPLIFIER MODULE, 29 - 36 GHz

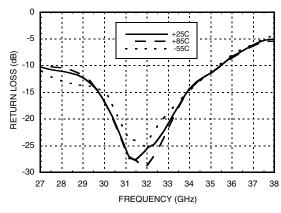
Broadband Gain & Return Loss



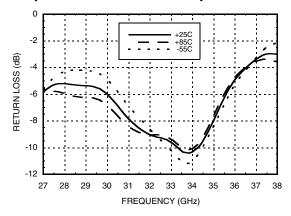
Gain vs. Temperature



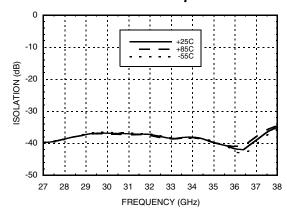
Input Return Loss vs. Temperature



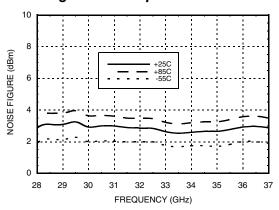
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



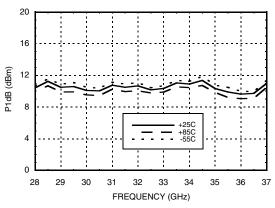
Noise Figure vs. Temperature



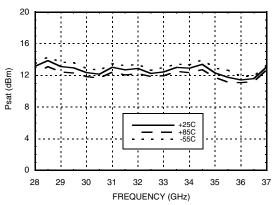


LOW NOISE AMPLIFIER **MODULE, 29 - 36 GHz**

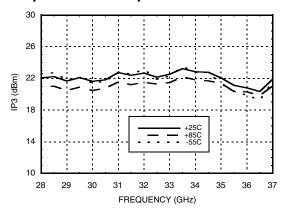
P1dB vs. Temperature



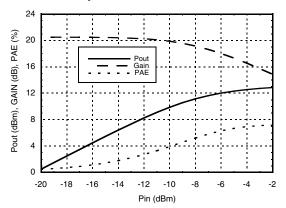
Psat vs. Temperature



Output IP3 vs. Temperature



Power Compression @ 32 GHz



Absolute Maximum Ratings

| Bias Supply Voltage (Vdc) | +3.5 Vdc |
|---------------------------|----------------|
| RF Input Power (RFIN) | +5 dBm |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -55 to +85 °C |







LOW NOISE AMPLIFIER MODULE, 29 - 36 GHz

Pin Descriptions

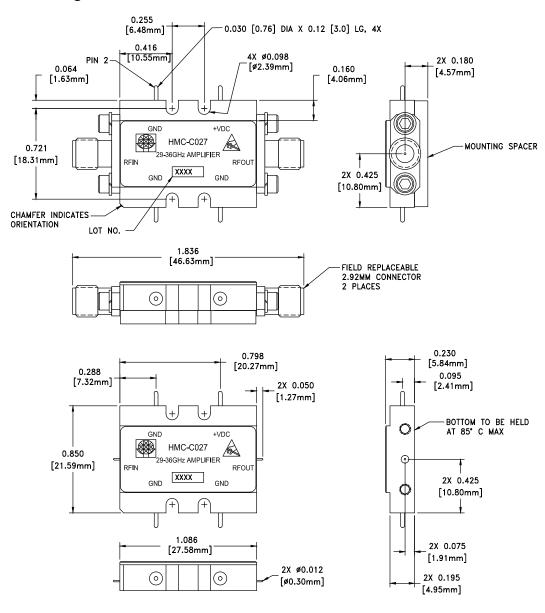
| Pin Number | Function | Description | Interface Schematic |
|------------|----------------------|--|---------------------|
| 1 | RFIN & RF Ground | RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms. | RFINO— - |
| 2, 5, 6 | GND | One of these pins must be connected to power supply ground. | ⊖ GND — — |
| 3 | Vdc | Power supply voltage for the amplifier. Includes zener diode for over voltage and negative voltage protection. | Vde O |
| 4 | RFOUT & RF Ground | RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms. | → → RFOUT |





LOW NOISE AMPLIFIER MODULE, 29 - 36 GHz

Outline Drawing



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED

Package Information

| Package Type | age Type C-10 | |
|--------------------|-------------------------|--|
| Package Weight [1] | 18.7 gms ^[2] | |
| Spacer Weight | 3.3 gms ^[2] | |

[1] Includes the connectors

[2] ±1 gms Tolerance

NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4 TOLERANCES:
 - $4.1 .XX = \pm 0.02$
- $4.2.XXX = \pm 0.010$
- 5. FIELD REPLACEABLE 2.92mm CONNECTORS TENSOLITE 231CCSF OR EQUIVALENT



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AMPLIFIERS





Notes:

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